NSN 5962-01-356-9162

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Milstar
Features Provided:
Electrostatic sensitive and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl and feat and nhcf
Case Outline Source And Designator:
F-9 mil-m-38510
Product Name:
Microcircuit, digital-cmos, 16k x 1 bit, static ram
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Memory Device Type:
Ram
Special Features:
Rad hard per raytheon g371916; ansi y14.5m-1982
Nuclear Hardness Critical Feature:
Hardened
Terminal Type And Quantity:
20 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0